

Dual-Output Remote-Junction Temperature Switches

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND

V_{DD} , $\overline{T}_{LOW}$, $\overline{T}_{HIGH}$	-0.3V to +6V
DXN	-0.3V to +0.8V
All Other Pins	-0.3V to (V_{DD} + 0.3V)
Input Current	5mA
Output Current	20mA

Continuous Power Dissipation ($T_A = +70^\circ\text{C}$)

8-Pin μMAX (derate 4.1mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$)	330mW
Operating Temperature Range	-40°C to $+125^\circ\text{C}$
Junction Temperature	$+150^\circ\text{C}$
Storage Temperature Range	-65°C to $+165^\circ\text{C}$
Lead Temperature (soldering, 10s)	$+300^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

($V_{DD} = 3.0\text{V}$ to 5.5V , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, unless otherwise noted. Typical values are at $V_{DD} = 3.3\text{V}$ and $T_A = +25^\circ\text{C}$.) (Note 1)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS
Power-Supply Range	V_{DD}		3.0		5.5	V
Average Supply Current	I_{DD}			200	500	μA
Supply Current During Conversion				400	800	μA
Power-On Reset Threshold	POR	V_{DD} falling edge	1.0	1.5	2.0	V
POR Threshold Hysteresis				50		mV
Temperature Threshold Accuracy	ΔT_{TH}	$V_{DD} = 3.3\text{V}$, $T_A = +25^\circ\text{C}$, $T_{RJ} = 0^\circ\text{C}$ to $+125^\circ\text{C}$ (Note 2)	-1.5		+1.5	$^\circ\text{C}$
		$T_A = 0^\circ\text{C}$ to $+100^\circ\text{C}$, $T_{RJ} = 0^\circ\text{C}$ to $+125^\circ\text{C}$		2.0		
Temperature Threshold Hysteresis	T_{HYST}			5.0		$^\circ\text{C}$
Supply Sensitivity of Temperature Threshold		$T_A = +25^\circ\text{C}$, $T_{RJ} = 0^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{DD} = 3.0\text{V}$ to 5.5V			0.6	$^\circ\text{C}/\text{V}$
Output Voltage High	V_{OH}	$I_{SOURCE} = 1\text{mA}$, MAX6685 $\overline{T}_{LOW}$ only	$V_{DD} - 0.2$			V
Output Voltage Low	V_{OL}	$I_{SINK} = 1\text{mA}$			0.2	V
Logic-Low Input Voltage	V_{IL}	S1, S2			0.4	V
Logic-High Input Voltage	V_{IH}	S1, S2	1.8			V
Input Current		S1, S2			10	μA
Open-Drain Output Leakage Current		$V_{OUT} = 5.5\text{V}$, $\overline{T}_{LOW}$ and $\overline{T}_{HIGH}$			1	μA
Conversion Time			0.09	0.11	0.13	s
Sample Period			0.35	0.45	0.55	s
Current Sourcing for External Diode		High level	80	100	120	μA
		Low level	8	10	12	

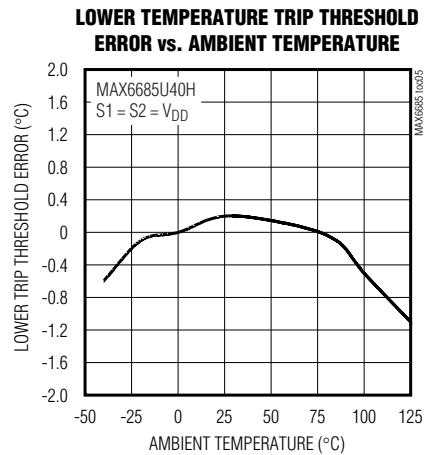
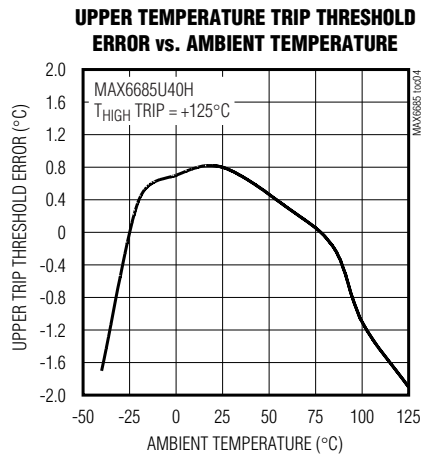
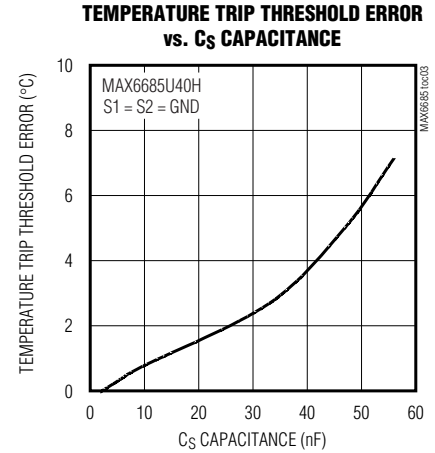
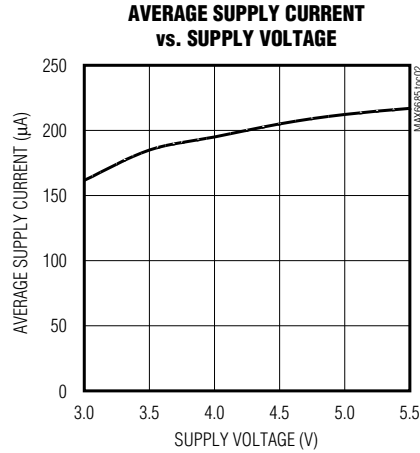
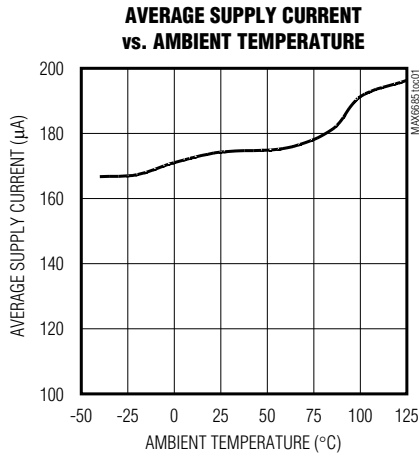
Note 1: All parameters are tested at $+25^\circ\text{C}$. Temperature specifications over a range of -40°C to $+125^\circ\text{C}$ are guaranteed by design.

Note 2: T_{RJ} is the temperature of the remote-sensing diode junction.

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Typical Operating Characteristics

($V_{DD} = 3.3V$, $C_S = 2200pF$, $T_A = +25^\circ C$, unless otherwise noted. See *Typical Operating Circuits*.)



MAX6685/MAX6686

Dual-Output Remote-Junction Temperature Switches

Pin Description

PIN		NAME	FUNCTION
MAX6685	MAX6686		
1	1	V _{DD}	Power-Supply Input. Bypass to GND with a 0.1μF capacitor.
2	2	GND	Ground
3	3	DXP	This pin connects to the positive (anode) terminal of the external P-N sense junction. It sources current into the external junction. A 2200pF capacitor should be connected across DXP and DXN.
4	4	DXN	This pin connects to the negative (cathode) terminal of the external P-N sense junction. It sinks current from the external junction. A 2200pF capacitor should be connected across DXP and DXN. DXN must be connected to the GND pin with the shortest possible connection.
5	5	$\overline{T}_{HIGH}$	Open-Drain, Active-Low Output. $\overline{T}_{HIGH}$ goes low when the temperature exceeds the factory-programmed upper temperature threshold, either +120°C or +125°C. Connect a pullup resistor (typically 10kΩ) between $\overline{T}_{HIGH}$ and a positive supply up to 5.5V.
6	—	T_{LOW}	CMOS Push-Pull, Active-High Output. T_{LOW} goes HIGH when the temperature exceeds the pin-programmed lower temperature threshold.
—	6	$\overline{T}_{LOW}$	Open-Drain, Active-Low Output. $\overline{T}_{LOW}$ goes LOW when the temperature exceeds the pin-programmed lower temperature threshold. Connect a pullup resistor (typically 10kΩ) between $\overline{T}_{LOW}$ and a positive supply up to 5.5V.
7	7	S1	Threshold Select Input. Used in conjunction with S2 to set the lower threshold for T_{LOW} (Table 1). It can be connected to V _{DD} , GND, or left floating.
8	8	S2	Threshold Select Input. Used in conjunction with S1 to set the lower threshold for T_{LOW} (Table 1). It can be connected to V _{DD} , GND, or left floating.

Detailed Description

The MAX6685/MAX6686 dual-output remote-sensing junction temperature switches incorporate a precision remote-junction temperature sensor and two comparators. These devices use an external P-N junction as the temperature-sensing element (see *Typical Operating Circuits*).

The MAX6685/MAX6686 provide noise immunity by integration and oversampling of the diode voltage, but good design practice includes routing the DXP and DXN lines away from noise sources, such as high-speed digital lines, switching regulators, inductors, and transformers. The DXP and DXN traces should be paired together and surrounded by a ground plane whenever possible.

The 5°C hysteresis keeps the outputs from “chattering” when the measured temperature is close to the threshold temperature. The MAX6685/MAX6686 are available with preset upper temperature thresholds of +120°C or +125°C. The lower temperature thresholds are pin programmable in 5°C increments (Table 1). Two tempera-

ture ranges are available for the lower trip threshold: +40°C to +80°C and +75°C to +115°C. S1 and S2 pins must be set to the desired trip temperature before power is applied to the V_{DD} pin. If this is done after the power is turned on, the lower trip threshold remains set to the point where S1 and S2 were when power was applied.

Applications Information

Remote-Diode Selection

The MAX6685/MAX6686 are optimized to measure the die temperature of CPUs and other ICs that have on-chip temperature-sensing diodes. These on-chip diodes are substrate PNPs with their collectors grounded. Connect the base of the PNP to DXN and the emitter to DXP. When using a discrete, diode-connected NPN or PNP as a sensing diode, use a good-quality small-signal device. Examples are listed in Table 2. Tight specifications for forward current gain indicate the manufacturer has good process controls and that the devices have consistent V_{be} characteristics. Always use a transistor for the sensing junction; diodes do not work.

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MAX6685/MAX6686

Table 1. Lower Temperature Trip Threshold Selection

S1	S2	MAX6685AUA40L MAX6685AUA40H MAX6686AUA40L MAX6686AUA40H	MAX6685AUA75L MAX6685AUA75H MAX6686AUA75L MAX6686AUA75H
		LOWER TEMPERATURE TRIP THRESHOLD (°C)	LOWER TEMPERATURE TRIP THRESHOLD (°C)
GND	GND	+40	+75
GND	FLOAT	+45	+80
GND	V _{DD}	+50	+85
FLOAT	GND	+55	+90
FLOAT	FLOAT	+60	+95
FLOAT	V _{DD}	+65	+100
V _{DD}	GND	+70	+105
V _{DD}	FLOAT	+75	+110
V _{DD}	V _{DD}	+80	+115

Noise-Filtering Capacitors

A quality ceramic capacitor must be connected across the DXP/DXN inputs to maintain temperature threshold accuracy by filtering out noise. The capacitor should be located physically close to the DXP/DXN pins and should typically have a value of 2200pF. Larger capacitor values can cause temperature measurement errors. A 50% variation from the recommended capacitor value can cause up to $\pm 1^{\circ}\text{C}$ error.

Table 2. Sensor Transistor Manufacturers

MANUFACTURER	MODEL NO.
Central Semiconductor (USA)	CMPT3904
ON Semiconductor (USA)	2N3904, 2N3906
Rohm Semiconductor (Japan)	SST3904
Samsung (Korea)	KST3904-TF
Siemens (Germany)	SMBT3904

Note: Discrete transistors must be diode connected (base shorted to collector).

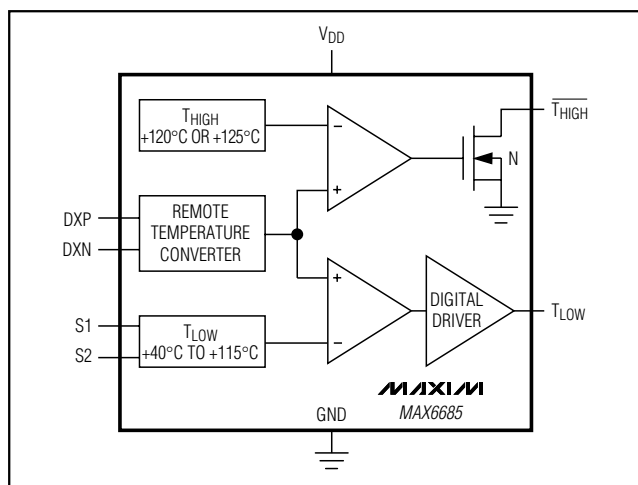


Figure 1. MAX6685 Functional Diagram

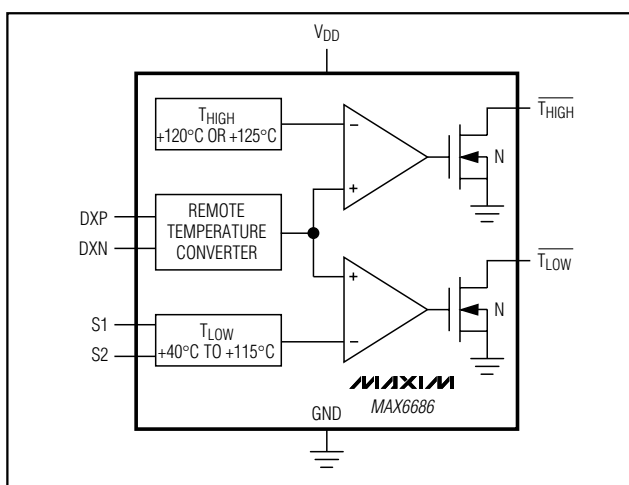
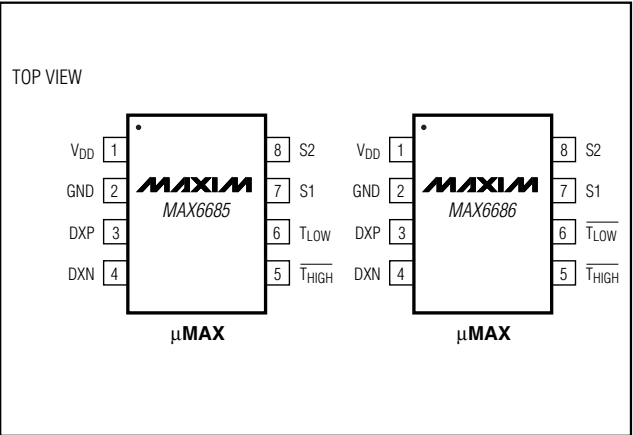


Figure 2. MAX6686 Functional Diagram

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Pin Configurations



Chip Information

TRANSISTOR COUNT: 7765
PROCESS: BiCMOS

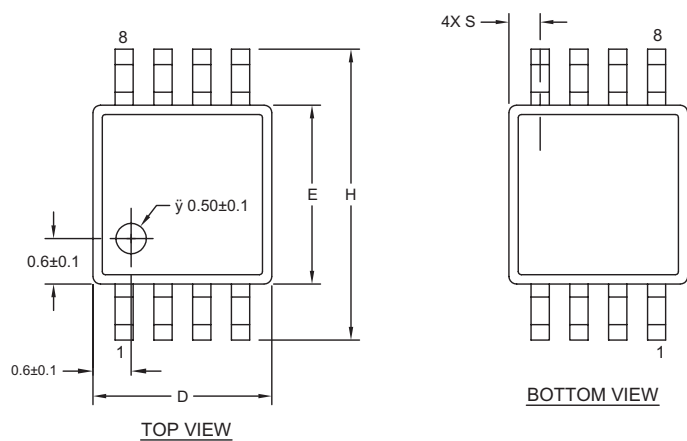
Dual-Output Remote-Junction Temperature Switches

Package Information

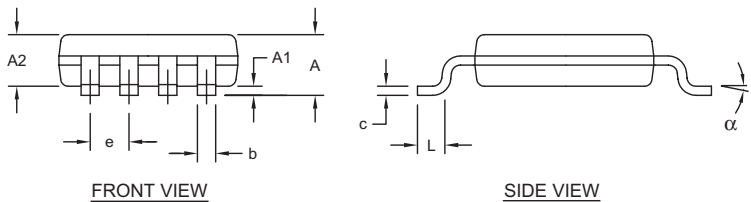
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

MAX6685/MAX6686

8LUMAXD.EPS



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	-	0.043	-	1.10
A1	0.002	0.006	0.05	0.15
A2	0.030	0.037	0.75	0.95
b	0.010	0.014	0.25	0.36
c	0.005	0.007	0.13	0.18
D	0.116	0.120	2.95	3.05
e	0.0256 BSC		0.65 BSC	
E	0.116	0.120	2.95	3.05
H	0.188	0.198	4.78	5.03
L	0.016	0.026	0.41	0.66
α	0°	6°	0°	6°
S	0.0207 BSC		0.5250 BSC	



- NOTES:
1. D&E DO NOT INCLUDE MOLD FLASH.
 2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15MM (.006").
 3. CONTROLLING DIMENSION: MILLIMETERS.
 4. MEETS JEDEC MO-187C-AA.

 DALLAS SEMICONDUCTOR			
PROPRIETARY INFORMATION			
TITLE: PACKAGE OUTLINE, 8L uMAX/uSOP			
APPROVAL	DOCUMENT CONTROL NO. 21-0036	REV. J	1 / 1

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